

L Number	Hits	Search Text	DB	Time stamp
-	2	rupture and oxide and (cmos with "0.13")	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2003/06/18 08:30
-	37	rupture and (oxide with (thickness or thick)) and (programming or programmable) and tunneling	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2003/06/17 15:05
-	925	cmos and (oxide same (tunnel or tunneling)) and write	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2003/06/17 15:10
-	0	cmos and (oxide same (tunnel or tunneling)) and (write with swith)	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2003/06/17 15:11
-	27	rupture and (cmos and (oxide same (tunnel or tunneling)) and write)	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2003/06/17 15:11
-	2	("4173791").PN.	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2003/06/18 08:33
-	5	("3744036"   "3836992"   "4012762"   "4051464"   "4070687").PN.	USPAT	2003/06/18 08:30
-	0	("antifusesameoxide").PN.	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2003/06/18 08:33
-	457	antifuse same oxide	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2003/06/18 08:34
-	3	memory and (("3744036"   "3836992"   "4012762"   "4051464"   "4070687").PN.)	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2003/06/18 09:25
-	249	memory and (antifuse same oxide)	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2003/06/18 08:35
-	87	(write or writing) and (memory and (antifuse same oxide))	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2003/06/18 08:41
-	2	("5,480,828").PN.	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2003/06/18 11:43
-	8	("4543594"   "4562639"   "4881114"   "4943538"   "5057451"   "5110754"   "5635873"   "5742555").PN.	USPAT	2003/06/18 09:04
-	8	5742555.URPN.	USPAT	2003/06/18 09:06

#17

-	28	("3600642"   "3883372"   "4394674"   "4543594"   "4689504"   "4730129"   "5112766"   "5252848"   "5278787"   "5296409"   "5306656"   "5334880"   "5369045"   "5371394"   "5374843"   "5399917"   "5414364"   "5420450"   "5434531"   "5465054"   "5514608"   "5514980"   "5536666"   "5574303"   "5578509"   "5583454"   "5661048"   "5776811").PN.	USPAT	2003/06/18 09:08
-	0	("storageand(writeorwirting)and(readreading, and antifuse	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM TDB	2003/06/18 09:14
-	0	storage and (writeorwirting) and (readreading) and antifuse	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM TDB	2003/06/18 09:15
-	311	storage and (write or wirting) and (read or reading) and antifuse	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM TDB	2003/06/18 09:15
-	131	oxide and (storage and (write or wirting) and (read or reading) and antifuse)	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM TDB	2003/06/18 09:21
-	132	("13" or "0.13" or "13") adj1 CMOS	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM TDB	2003/06/18 09:22
-	61	memory and (("13" or "0.13" or "13") adj1 CMOS)	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM TDB	2003/06/18 09:25
-	42	5480828.URPN.	USPAT	2003/06/18 09:51
-	0	("antifuseand(readadjlmemoryorrom)andwriteand(USPAT).PN.	US-PGPUB; EPO; JPO; DERWENT; IBM TDB	2003/06/18 11:44
-	76	antifuse and (read adj1 memory or rom)and write and oxide	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM TDB	2003/06/18 14:38
-	38	antifuse same source same drain same (tub or well)	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM TDB	2003/06/18 14:39